NSN 5961-00-412-2376

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View Online at https://aerobasegroup.com/nsn/5961-00-412-2376 **Inclosure Material:** Metal **Overall Length:** 0.480 inches **Overall Diameter:** 0.785 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Threaded stud **Features Provided:** Mounting hardware **Overall Width Across Flats:** 0.875 inches **Thread Size:** 0.312 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 175.0 collector to emitter voltage/static/base open and 175.0 breakdown voltage, collector-to-base, emitter open and 5.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 20.00 amperes source cutoff current and 5.00 amperes source cutoff current **Power Rating Per Characteristic:** 175.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Precious Material And Location:** Terminals gold **Precious Material:** Gold

Shelf Life:

N/a

Unf

Thread Series Designator:

Terminal Type And Quantity: 1 wire hook and 2 tab, solder lug

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Demilitarization:

No

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